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HMC416LP4 / 416LP4E

v02.0805



MMIC VCO w/ BUFFER AMPLIFIER, 2.75 - 3.0 GHz

Typical Applications

Low noise MMIC VCO w/Buffer Amplifier for:

- Wireless Infrastructure
- Industrial Controls
- Test Equipment
- Military

Features

Pout: +4.5 dBm

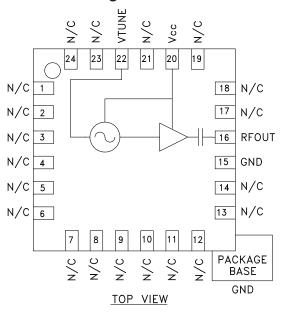
Phase Noise: -114 dBc/Hz @100 k Hz

No External Resonator Needed

Single Supply: 3V @ 37 mA

QFN Leadless SMT Package, 16 mm²

Functional Diagram



General Description

The HMC416LP4 & HMC416LP4E are GaAs InGaP Heterojunction Bipolar Transistor (HBT) MMIC VCOs with integrated resonators, negative resistance devices, varactor diodes, and buffer amplifiers. Covering 2.75 to 3.0 GHz, the VCO's phase noise performance is excellent over temperature, shock, vibration and process due to the oscillator's monolithic structure. Power output is 4.5 dBm typical from a single supply of 3V @ 37 mA. The voltage controlled oscillator is packaged in a low cost leadless QFN 4 x 4 mm surface mount package.

Electrical Specifications, $T_A = +25^{\circ}$ C, Vcc = +3V

Parameter	Min.	Тур.	Max.	Units
Frequency Range		2.75 - 3.0		GHz
Power Output	1.5	4.5		dBm
SSB Phase Noise @ 100 kHz Offset, Vtune= +5V @ RF Output		-114		dBc/Hz
Tune Voltage (Vtune)	0		10	V
Supply Current (Icc) (Vcc = +3.0V)		37		mA
Tune Port Leakage Current			10	μΑ
Output Return Loss		9		dB
Harmonics 2nd 3rd		-5 -16		dBc dBc
Pulling (into a 2.0:1 VSWR)		3		MHz pp
Pushing @ Vtune= +5V		-1		MHz/V
Frequency Drift Rate		0.3		MHz/°C

HMC416* PRODUCT PAGE QUICK LINKS

Last Content Update: 02/23/2017

COMPARABLE PARTS 🖵

View a parametric search of comparable parts.

EVALUATION KITS

· HMC416LP4 Evaluation Board

DOCUMENTATION

Application Notes

 Determining the FM Bandwidth of a Wideband Varactor Tuned VCO

Data Sheet

· HMC416 Data Sheet

REFERENCE MATERIALS 🖳

Quality Documentation

- Package/Assembly Qualification Test Report: LP4, LP4B, LP4C, LP4K (QTR: 2013-00487 REV: 04)
- Package/Assembly Qualification Test Report: Plastic Encapsulated QFN (QTR: 05006 REV: 02)
- Semiconductor Qualification Test Report: GaAs HBT-A (OTR: 2013-00228)

DESIGN RESOURCES

- HMC416 Material Declaration
- PCN-PDN Information
- · Quality And Reliability
- Symbols and Footprints

DISCUSSIONS

View all HMC416 EngineerZone Discussions.

SAMPLE AND BUY

Visit the product page to see pricing options.

TECHNICAL SUPPORT

Submit a technical question or find your regional support number.

DOCUMENT FEEDBACK \Box

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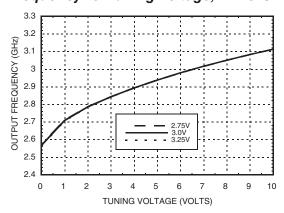
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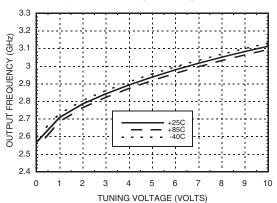


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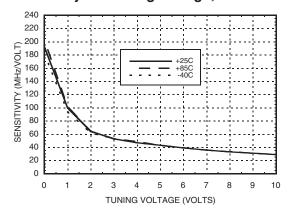
Frequency vs. Tuning Voltage, T= 25°C



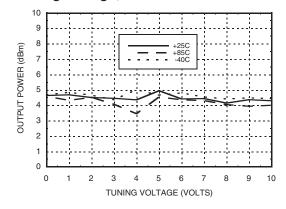
Frequency vs. Tuning Voltage, Vcc= +3V



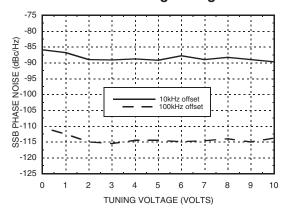
Sensitivity vs. Tuning Voltage, Vcc= +3V



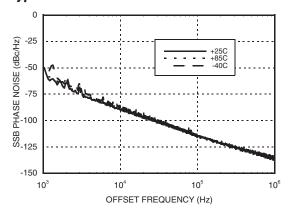
Output Power vs. Tuning Voltage, Vcc= +3V



Phase Noise vs. Tuning Voltage



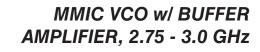
Typical SSB Phase Noise @ Vtune= +5V





RoHS√

v02.0805



Absolute Maximum Ratings

Vcc	+3.5 Vdc	
Vtune	0 to +11V	
Channel Temperature	135 °C	
Continuous Pdiss (T = 85°C) (derate 3.6 mW/°C above 85°C)	180 mW	
Thermal Resistance (R _{TH}) (junction to package base)	277 °C/W	
Storage Temperature	-65 to +150 °C	
Operating Temperature	-40 to +85 °C	

Typical Supply Current vs. Vcc

Vcc (V)	Icc (mA)	
2.75	32	
3.0	37	
3.25	42	

Note: VCO will operate over full voltage range shown above.



ELECTROSTATIC SENSITIVE DEVICE OBSERVE HANDLING PRECAUTIONS

Outline Drawing

BOTTOM VIEW PIN 24 -.016 [0.40] REF 0.30 .008 [0.20] MIN 19 PIN 1 18 HNNN XXXX 13 EXPOSED GROUND PADDLE LOT NUMBER MUST BE CONNECTED TO RF/DC GROUND **SQUARE** 0.05 SEATING

- 1. LEADFRAME MATERIAL: COPPER ALLOY
- 2. DIMENSIONS ARE IN INCHES [MILLIMETERS]
- 3. LEAD SPACING TOLERANCE IS NON-CUMULATIVE.
- 4. PAD BURR LENGTH SHALL BE 0.15mm MAXIMUM. PAD BURR HEIGHT SHALL BE 0.05mm MAXIMUM.
- 5. PACKAGE WARP SHALL NOT EXCEED 0.05mm.
- 6. ALL GROUND LEADS AND GROUND PADDLE MUST BE SOLDERED TO PCB RF GROUND.
- 7. REFER TO HITTITE APPLICATION NOT FOR SUGGESTED LAND PATTERN.

Package Information

.003[0.08]|C

Part Number	Package Body Material	Lead Finish	MSL Rating	Package Marking [3]
HMC416LP4	Low Stress Injection Molded Plastic	Sn/Pb Solder	MSL1 [1]	H416 XXXX
HMC416LP4E	RoHS-compliant Low Stress Injection Molded Plastic	100% matte Sn	MSL1 [2]	H416 XXXX

PLANE

-C-

- [1] Max peak reflow temperature of 235 °C
- [2] Max peak reflow temperature of 260 °C
- [3] 4-Digit lot number XXXX





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Pin Descriptions

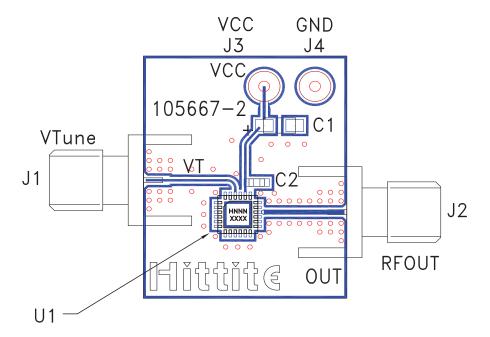
Pin Number	Function	Description	Interface Schematic
1- 14, 17 - 19, 21, 23, 24	N/C	No Connection. These pins may be connected to RF ground. Performance will not be affected.	
15	GND	This pin must be connected to RF & DC ground.	→ GND =
16	RFOUT	RF output (AC coupled)	—
20	Vcc	Supply Voltage Vcc= 3V	Vcc O26pF
22	VTUNE	Control Voltage Input. Modulation port bandwidth dependent on drive source impedance.	10nH 50 \(\text{C};=\) 4.6pF \(\frac{1}{2} \) 3.2pF
	GND	Package bottom has an exposed metal paddle that must be RF & DC grounded.	○ GND =





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Evaluation PCB



List of Materials for Evaluation PCB 105706 [1]

Item	Description	
J1 - J2	PCB Mount SMA RF Connector	
J3 - J4	DC Pin	
C1	4.7 μF Tantalum Capacitor	
C2	10,000 pF Capacitor, 0603 Pkg.	
U1	HMC416LP4 / HMC416LP4E VCO	
PCB [2]	105667 Eval Board	

^[1] Reference this number when ordering complete evaluation PCB

The circuit board used in the final application should use RF circuit design techniques. Signal lines should have 50 ohm impedance while the package ground leads and exposed paddle should be connected directly to the ground plane similar to that shown. A sufficient number of via holes should be used to connect the top and bottom ground planes. The evaluation circuit board shown is available from Hittite upon request.

^[2] Circuit Board Material: Rogers 4350



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Notes:

RoHS√